

# Thermal expansion of nanocrystalline boron carbide

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## Abstract

The lattice thermal expansion behaviour of nanocrystalline and microcrystalline boron carbides has been measured by high temperature X-ray diffraction technique in the temperature range 298–1773 K. The lattice parameters of both were found to increase with increase in temperature. The average thermal expansion coefficients in this temperature range for the nanocrystalline and the microcrystalline boron carbides were found to be  $7.76 \times 10^{-6}$  and  $7.06 \times 10^{-6} \text{ K}^{-1}$ , respectively. The difference observed in the thermal expansion behaviour is probably due to increase in the surface energy of the lattice in the nanocrystalline material.

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## 1. Introduction

Boron carbide is the third hardest material after diamond and cubic boron nitride. However, at temperatures above 1373 K, it is the hardest known material [1–3]. This property, coupled with its low density, high hardness, high Young's modulus, and chemical inertness to acids, makes it a potential candidate for use in high technology applications that include abrasives for polishing and grinding media, ceramic armor for personnel and equipment, blasting nozzles, ceramic bearings and wire drawing dies [4–6]. The  $^{10}\text{B}$  isotope, present in natural boron (19.5 at.%) has a high absorption cross section for thermal neutrons and moderate cross section for fast neutrons. Hence boron carbide (enriched in  $^{10}\text{B}$  isotope) is used in the manufacture of control rods and neutron shields for nuclear reactors [7–12].

Temperature changes in materials cause dimensional changes so as to minimise free energy of the system [13]. Lattice vibrations, free electron transitions, electric and magnetic dipole etc. contribute to the free energy. However, the largest contribution to the free energy, at moderate and high

temperatures, is from the lattice vibrations. The thermal expansion of solid is a manifestation of the anharmonic nature of the lattice vibrations. Due to the anharmonic component in the lattice vibrations, the interatomic separations increase with increase in temperature. These changes in the interatomic separations are reflected in the changes in the values of lattice parameters. Hence by measuring the lattice parameters as a function of temperature, the coefficient of thermal expansion ( $\alpha$ ) of crystalline materials can be obtained. Accurate values of thermal expansion are useful for various industrial applications of new materials. Thermal expansion measurements are necessary in the temperature range of interest in order to address problems such as thermally induced stresses between dissimilar materials in contact. In this regard, the thermal expansion of nuclear fuels, neutron absorbers, and clad materials is important in determining their performance in the nuclear reactor. In addition, data on  $\alpha$  are needed to derive heat capacity at constant volume ( $C_v$ ) from the experimentally measured heat capacity at constant pressure ( $C_p$ ) [14,15].

Nanocrystalline materials are single or multiphase polycrystalline solids with a grain size of a few nanometers, typically less than 100 nm [16,17]. They have been the subject of intense research due to their potential applications in a wide variety of technological areas such as electronics, catalysis, ceramics, magnetic data storage, structural components etc. These materials exhibit unique, extraordinary physical and chemical properties relative to the corresponding properties

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present in bulk materials viz., increased mechanical strength, enhanced diffusivity, higher specific heat and electrical resistivity [18]. Since the grain sizes are small, a large volume fraction (>50%) of the atoms reside in grain boundaries. The interface or grain boundary structure plays an important role in determining the physical and chemical properties of nanocrystalline materials [19].

Both theoretical and experimental data on the thermal expansion of various nanocrystalline materials are reported in the literature [20–22]. Theoretical studies show that  $\alpha$  increases with decrease in crystallite size [20]. Klam et al. [21] and Lu et al. [22] have reported such a behaviour for copper and nanocrystalline Ni–P alloys, respectively. However, in some cases it was observed to be independent of the crystallite size [20].

Information on the high-temperature thermal expansion characteristics of boron carbide is very limited. Thevenot [23] in his review has reported the average  $\alpha$  of boron carbide to be  $4\text{--}8 \times 10^{-6} \text{ K}^{-1}$  in the temperature range 298–1073 K. Yakel [24] has measured the  $\alpha$  of boron carbides in the temperature range 285–1213 K, by using high temperature X-ray diffraction (HT-XRD) technique and reported the values to be  $5.65 \times 10^{-6} \text{ }^\circ\text{C}^{-1}$  and  $5.87 \times 10^{-6} \text{ }^\circ\text{C}^{-1}$  for a carbon rich boron carbide phase and a boron rich boron carbide phase, respectively. Tsagareishvili et al. [25] also measured the  $\alpha$  of boron carbide in the temperature range 298–1213 K by using the HT-XRD technique and reported a value of  $5.73 \times 10^{-6} \text{ K}^{-1}$ . However, data on the thermal expansion of nanocrystalline boron carbide are not available in the literature.

In the present study, thermal expansion values of both nanocrystalline and microcrystalline boron carbides were measured by HT-XRD technique. The experimentally measured data for the nanocrystalline boron carbide are compared with those obtained for microcrystalline boron carbide.

## 2. Experimental

### 2.1. Sample preparation

Boric acid (99% pure) procured from M/s Paramount Chemicals, Chennai, India and sucrose (AR grade) obtained from M/s Hi Pure Fine Chemicals, Chennai, India, were used for the preparation of nanocrystalline boron carbide by gel-pyrolysis method. In this method, a xerogel was prepared by dissolving boric acid in molten sucrose. This xerogel upon decomposition at 1273 K yielded a precursor that contained a homogeneous mixture of boric oxide and carbon. This precursor upon further heating at 1823 K for 3 h yielded nanocrystalline boron carbide. The constituent phases present in this precursor and the final product were identified by using X-ray diffraction technique (XRD) while their elemental composition was established by chemical analyses. The preparation methodology is illustrated elsewhere [26].

Microcrystalline boron carbide prepared by conventional carbothermic reduction method was obtained from M/s. Boron Carbide India Pvt., Ltd, Mumbai, India.

### 2.2. X-ray diffraction studies

The XRD experiment was performed by using Cu K $\alpha$  radiation ( $\lambda = 0.154 \text{ nm}$ ), in a Philips X'pert MPD system equipped with a graphite monochromator. The XRD pattern was recorded in the two theta range,  $10 \leq 2\theta \leq 60$ . Peak positions and the relative intensities were estimated by using the peak fit programme of the Philips X'pert plus software. The calibration of the diffractometer was carried out by using silicon and  $\alpha$ -alumina standards obtained from the National Institute of Standards and Technology (NIST), USA. Crystallite size of boron carbide was calculated by using the Scherrer's formula  $L = 0.94\lambda/\beta\cos\theta$ , where  $L$  = crystallite size,  $\lambda$  = wave length of the X-rays used,  $\beta$  = peak width (Full Width at Half Maximum) (FWHM), and  $\theta$  = Bragg angle [27].

### 2.3. Chemical analyses

#### 2.3.1. Analysis of boron

Amount of boron in boron carbide sample was quantitatively estimated by using the sodium carbonate fusion technique [28]. In a typical estimation, about 100 mg of the sample was fused with about 5 g of sodium carbonate in a platinum crucible at 1223 K. The product was cooled and dissolved in about 25 mL of 3.5 M hydrochloric acid and made up with distilled water in a 100 mL standard volumetric flask. Boron present in this solution was estimated as borate by titrating it as mannitol–boric acid complex against standard sodium hydroxide solution (0.1 M) by using phenolphthalein as indicator.

#### 2.3.2. Carbon analysis

The carbon present in boron carbide was determined by oxidising the sample in a stream of oxygen and measuring the amount of carbon dioxide thus evolved by using an infrared detector. The analysis was standardised by analysing anhydrous  $\text{CaCO}_3$ .

### 2.4. Thermal expansion studies

The thermal expansion of boron carbide was measured from 298 to 1773 K by using the HT-XRD technique. The HT-XRD measurements were performed by using a Philips-X'pert MPD system, equipped with the Buhler's high vacuum heating stage. The heating stage consisted of a thin ( $\sim 80 \text{ }\mu\text{m}$  thickness) resistively heated tantalum foil, on top of which the sample was placed. The temperature was measured by a W–Re thermocouple, which was spot-welded to the bottom of the tantalum heater. The temperature was controlled to an accuracy of about  $\pm 1 \text{ K}$  using a Proportional-Integral-Derivative (PID) controller. The diffraction studies were performed by using Cu K $\alpha$  radiation in the Bragg-Brentano geometry, at a temperature interval of 50 K up to 1773 K. A heating rate of  $1 \text{ K min}^{-1}$  and a holding time of 60 min at each temperature of measurement were adopted. The specimen stage was flushed with high purity argon before the start of every experimental run and a vacuum level of about  $10^{-5} \text{ mbar}$  was maintained throughout the experiment. Typical operating conditions for recording XRD

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